

Less Noisy & Highly Sensitive Graphene N-pores for Ultra-fast DNA Sequencing

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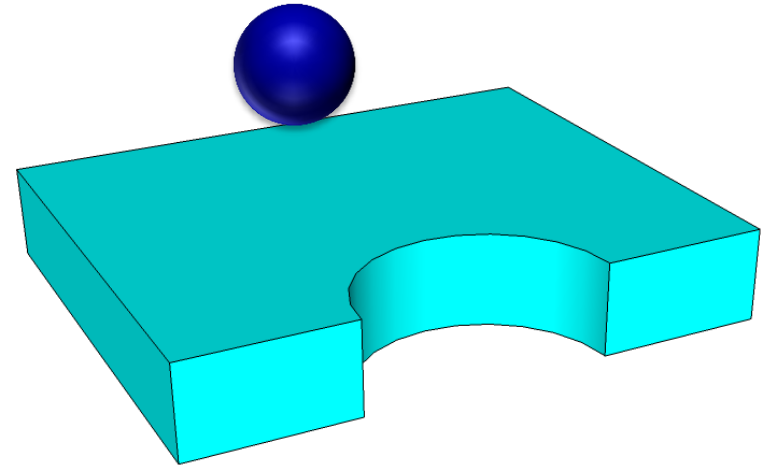
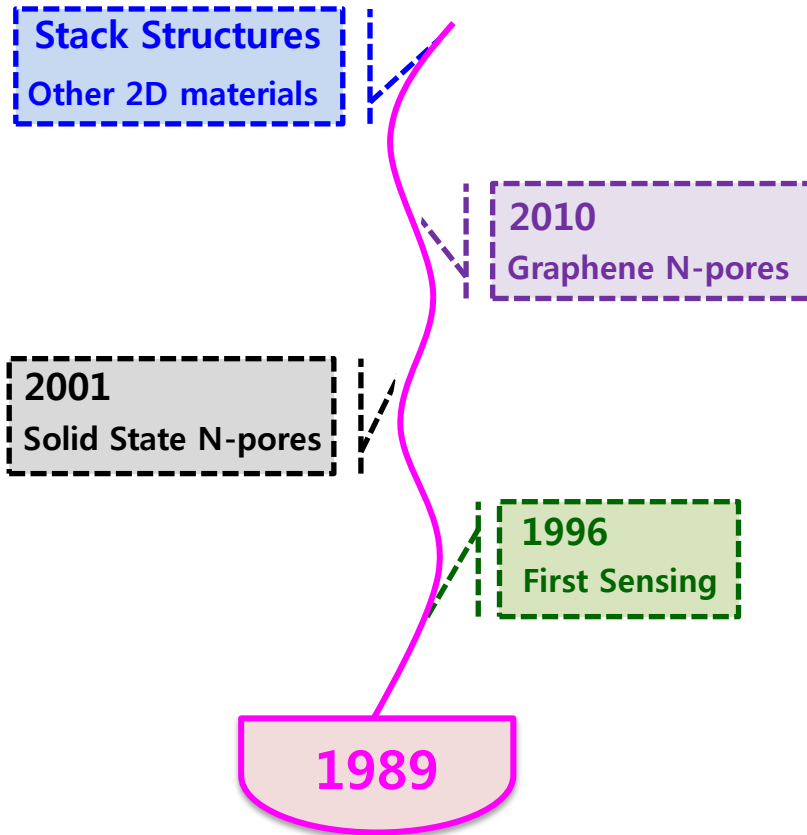
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Origin & Concept of Nanopore



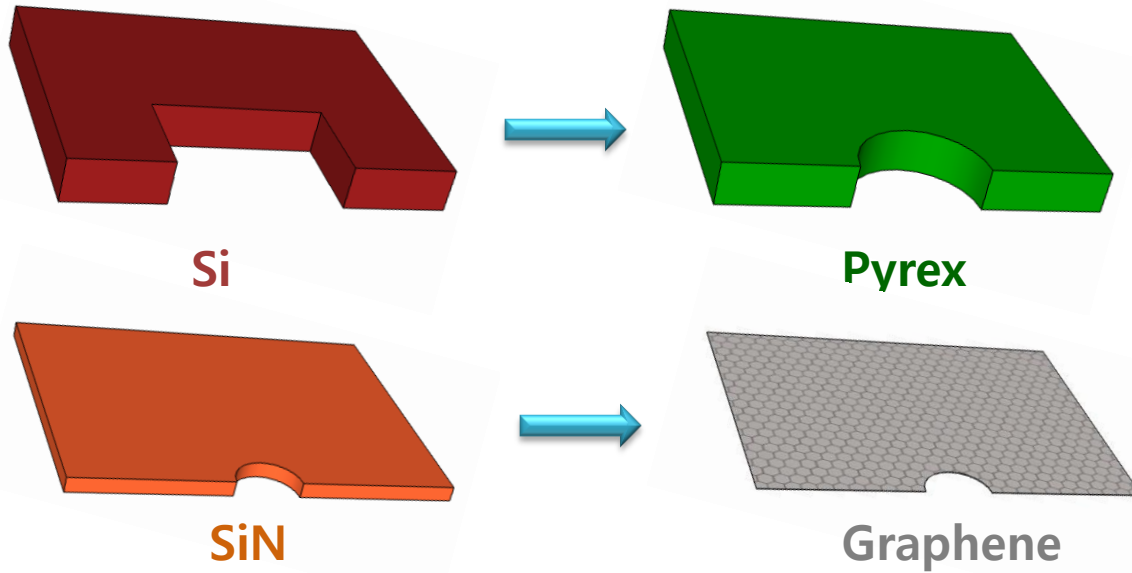
Higher Ionic Current Noise

Limited Bandwidth

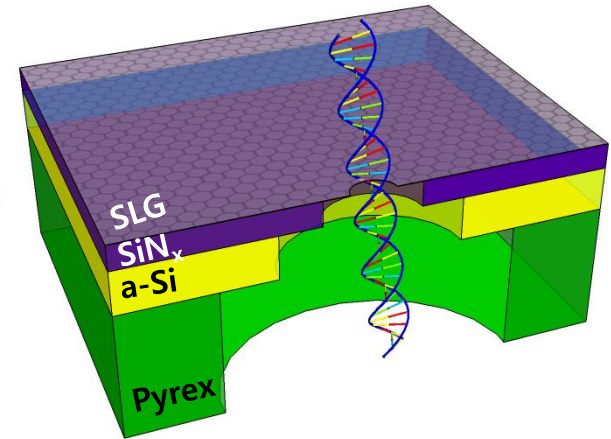
Signal to Noise Ratio

Resolution

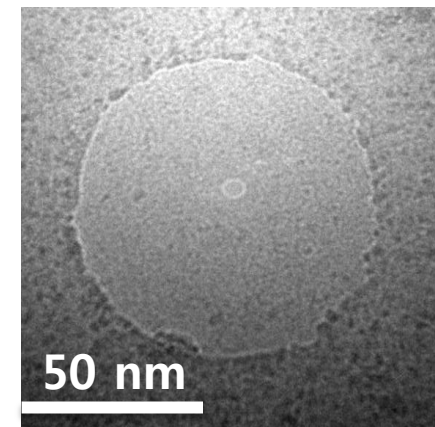
Approach towards improving solid-state nanopores



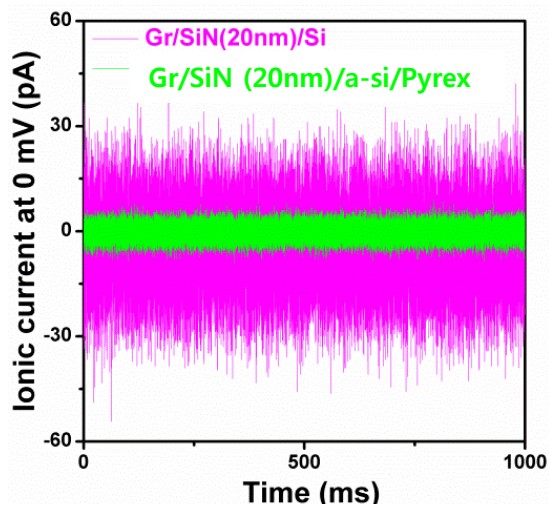
| Materials | ϵ | D_{loss} |
|-----------|------------|----------------------------|
| Si | 11.8 | $5 \sim 15 \times 10^{-3}$ |
| Pyrex | 4.6 | 1×10^{-3} |



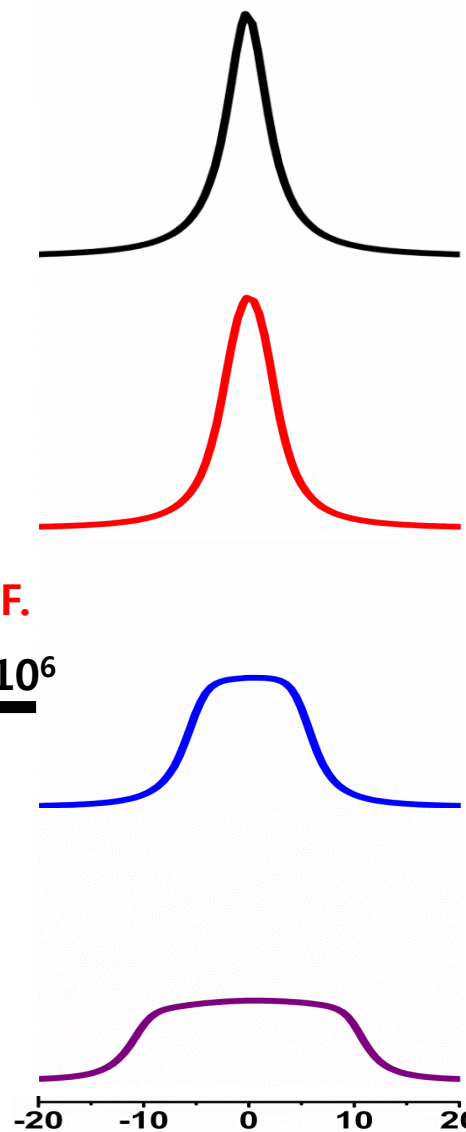
| Materials | Dimensions | Purpose |
|------------------|---|--|
| a-Si/Pyrex | Pore size ($5 \times 5 \mu\text{m}^2$) | ✓ Dielectric noise reduction |
| SiN _x | Th. = 20 nm | Reduces: ✓ Graphene layer fluctuations ✓ Pin-hole effects |
| | $\Phi = 70\text{-}80\text{nm}$ | |
| Graphene | 0.3-3.0nm | ✓ Improved spatial resolution ✓ Better sensing capability |
| | $\Phi = 5\text{-}6 \text{ nm}$ | |



Improved noise characteristics and temporal resolution

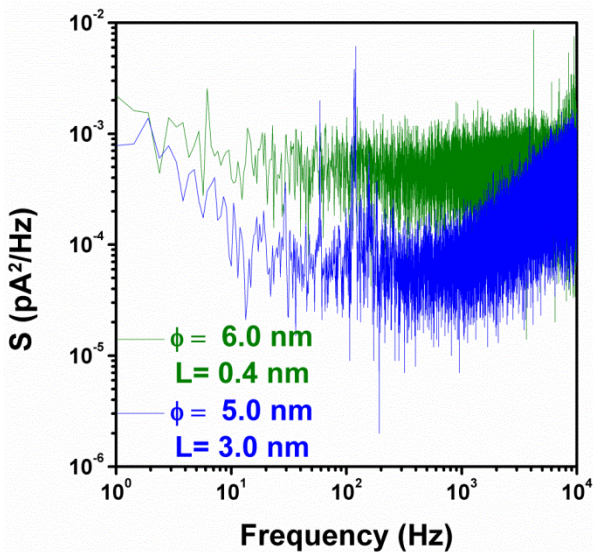


| Noise parameters | Gr/SiN/Si | Gr/SiN/Pyrex |
|------------------|-----------------------|-----------------------|
| A | 1.3×10^{-1} | 6.1×10^{-3} |
| B | 3.9×10^{-2} | 8.6×10^{-5} |
| C | 4.6×10^{-6} | 1.6×10^{-7} |
| D | 3.5×10^{-10} | 1.2×10^{-11} |
| β | 1 | 1 |
| I_{rms} (pA) | 18 | 2.7 |

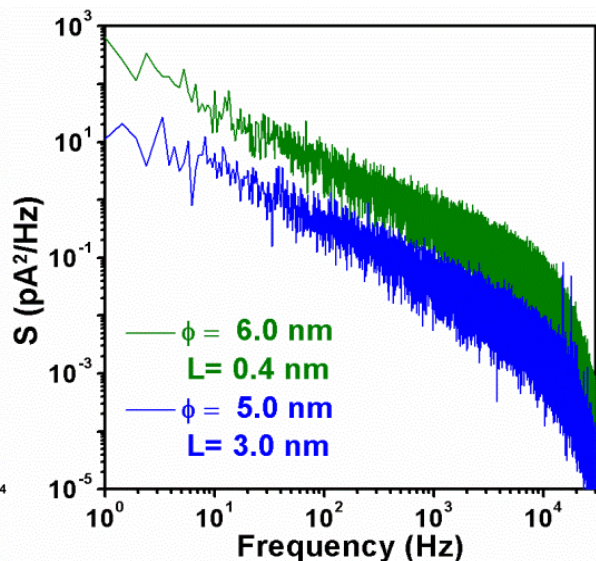


E.F.

5×10^6



$I_{rms} = 4.7 \text{ pA (SLG)}$
 $= 2.3 \text{ pA (FLG)}$



$I_{rms} = 77 \text{ pA (SLG)}$
 $= 14 \text{ pA (FLG)}$

Summary

- ✓ Pyrex based device posses low noise level as compared to Si based device
- ✓ This graphene nanopore presents lower noise level than reported
- ✓ Few layer graphene shows
 - Low noise level
 - Better SNR
 - Increased blockade current
 - Better mechanical stability and easy pore formation

THANK YOU